

DTQ6336 www.din-tek.jp

**RoHS** COMPLIANT

# N-Channel 30 V (D-S) MOSFET

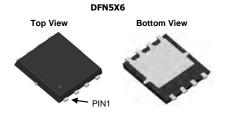
PRODUCT SUMMARY						
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>a, e</sup>	Q <sub>g</sub> (Typ.)			
30	0.0047 at V <sub>GS</sub> = 10 V	70	47nC			
30	0.0076 at V <sub>GS</sub> = 4.5 V	58	4/110			

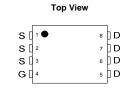
### **FEATURES**

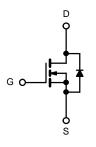
- DT-Trench Power MOSFET
- 100 % R<sub>g</sub> and UIS Tested

#### **APPLICATIONS**

- Notebook PC Core
- VRM/POL ٠







N-Channel MOSFET

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V <sub>DS</sub>	30	V		
Gate-Source Voltage		V <sub>GS</sub>	± 20	V	
	T <sub>C</sub> = 25 °C		70 <sup>a, e</sup>		
Continuous Drain Current (T <sub>J</sub> = 175 °C)	T <sub>C</sub> = 70 °C		58 <sup>e</sup>		
Continuous Drain Current (1) = 175 C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	16 <sup>b, c</sup>	A	
	T <sub>A</sub> = 70 °C		10.1 <sup>b, c</sup>		
Pulsed Drain Current	I <sub>DM</sub>	210	1		
Avalanche Current Pulse	L = 0.1 mH	I <sub>AS</sub>	65	7	
Single Pulse Avalanche Energy	L = 0.1 mm	E <sub>AS</sub>	51	mJ	
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25 °C	I <sub>S</sub>	70 <sup>a, e</sup>	A	
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	15	2.62 <sup>b, c</sup>		
	T <sub>C</sub> = 25 °C		190 <sup>a</sup>		
Maximum Power Dissipation	T <sub>C</sub> = 70 °C	PD	145	w	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	U I	3.55 <sup>b, c</sup>		
	T <sub>A</sub> = 70 °C		2.33 <sup>b, c</sup>		
Operating Junction and Storage Temperature R	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient <sup>b, d</sup>	$t \le 10 \text{ s}$	R <sub>thJA</sub>	45	55	°C/W		
Maximum Junction-to-Case Steady S		R <sub>thJC</sub>	0.8	1.0	0/10		

Notes:

a. Based on  $T_C = 25 \text{ °C}$ . b. Surface mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. Maximum under steady state conditions is 90 °C/W.

e. Calculated based on maximum junction temperature. Package limitation current is 70 A.

Parameter	Symbol	Test Conditions	Min .	Тур.	Max.	Unit
Static			•			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$	30			V
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	$I_{\rm DS}/T_{\rm J}$ $I_{\rm D} = 250 \mu {\rm A}$		35		mV/°C
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 5.5		mv/-C
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	0.8		2.5	V
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zara Cata Valtaga Drain Current	I <sub>DSS</sub>	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA
Zero Gate Voltage Drain Current		$V_{DS}$ = 24 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C			10	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	90			А
	P	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$		0.0047	0.006	Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS}$ = 4.5 V, I <sub>D</sub> = 20 A		0.0076	0.009	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 30 A		135		S
Dynamic <sup>b</sup>						
Input Capacitance	C <sub>iss</sub>			3490		
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ = 24 V, $V_{GS}$ = 0 V, f = 1 MHz		1125		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			770		
Total Gate Charge	Qg	$V_{DS} = 24$ V, $V_{GS} = 10$ V, $I_{D} = 30$ A		47		nC
				31		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 24 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 20 A		14		
Gate-Drain Charge	Q <sub>gd</sub>			19		
Gate Resistance	Rg	f = 1 MHz		1.4	2.1	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			25		ns
Rise Time	t <sub>r</sub>	$V_{DD}$ = 24 V, $R_L$ = 0.555 $\Omega$		13		
Turn-Off Delay Time	t <sub>d(off)</sub>	${\rm I_D}{\cong}30$ A, ${\rm V_{GEN}}$ = 10 V, ${\rm R_g}$ = 1 $\Omega$		75		
Fall Time	t <sub>f</sub>			10		
Turn-On Delay Time	t <sub>d(on)</sub>			58		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 24 V, $R_L$ = 0.625 $\Omega$		183		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D} \cong$ 20 A, $\text{V}_\text{GEN}$ = 4.5 V, $\text{R}_\text{g}$ = 1 $\Omega$		55		
Fall Time	t <sub>f</sub>			14		
Drain-Source Body Diode Characteristic	s					
Continuous Source-Drain Diode Current	۱ <sub>S</sub>	T <sub>C</sub> = 25 °C			70	A
Pulse Diode Forward Current <sup>a</sup>	I <sub>SM</sub>				210	
Body Diode Voltage	$V_{SD}$	I <sub>S</sub> = 10 A		0.7	1.2	V
Body Diode Reverse Recovery Time	t <sub>rr</sub>			52	73	ns
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> = 20 A, di/dt = 100 A/μs, Τ <sub>J</sub> = 25 °C		65	102	nC
Reverse Recovery Fall Time	t <sub>a</sub>	$r_F = 20 \text{ A}, \text{ avat} = 100 \text{ Avps}, r_J = 25 ^{\circ}\text{C}$		27		
Reverse Recovery Rise Time	t <sub>b</sub>	_		20		ns

Notes:

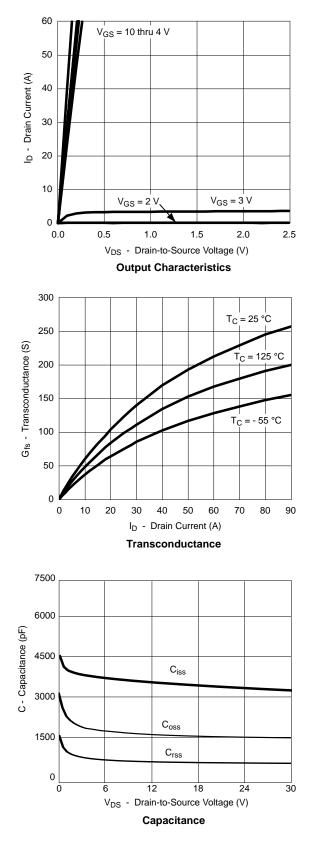
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

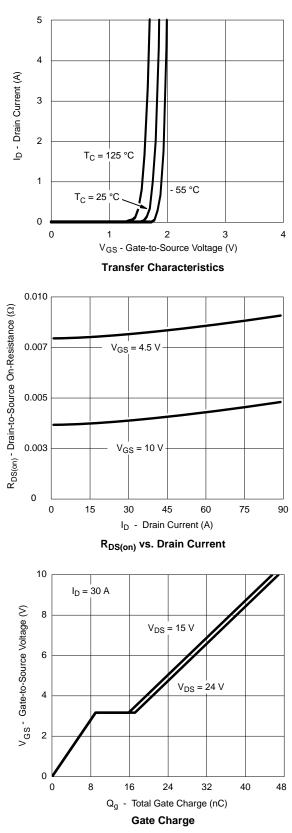
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

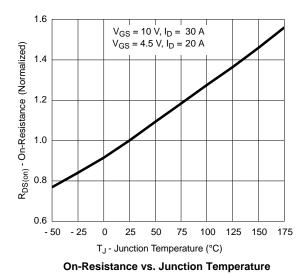


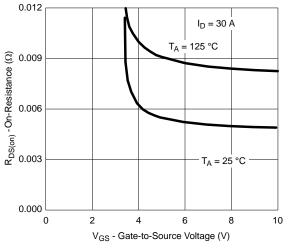




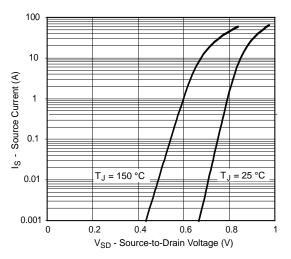
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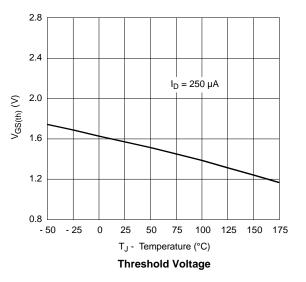


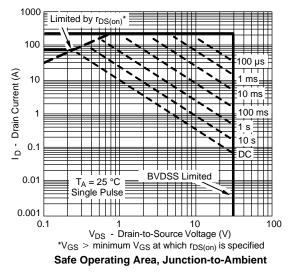


 $R_{\text{DS(on)}}$  vs.  $V_{\text{GS}}$  vs. Temperature



Forward Diode Voltage vs. Temperature

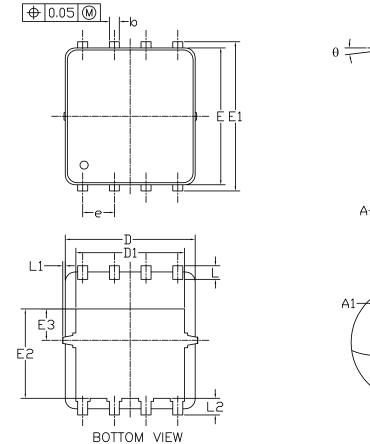




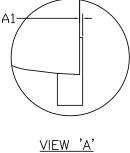
С

VIEW 'A'

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DFN5x6\_8L\_EP1\_P PACKAGE OUTLIN



(SCALE 5:1)

0.50 + - 4.60 - 0.55 0.50 + - 0.77 - 0.55 0.55 + - 0.635 + 0.635

+

+

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+

-11.27-

**RECOMMENDED LAND PATTERN** 

SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
STNBOLS	MIN	NOM	MAX	MIN	NOM	MAX
А	0.85	0.95	1.00	0.033	0.037	0.039
A1	0.00		0.05	0.000		0.002
b	0.30	0.40	0.50	0.012	0.016	0.020
с	0.15	0.20	0.25	0.006	0.008	0.010
D	4.80	5.20	5.30	0.201	0.205	0.209
D1	4.25	4.35	4.45	0.167	0.171	0.175
Е	5.45	5.55	5.65	0.215	0.219	0.222
E1	5.95	6.05	6.15	0.234	0.238	0.242
E2	3.525	3.625	3.725	0.139	0.143	0.147
E3	1.175	1.275	1.375	0.046	0.050	0.054
e	1.27 BSC			0.050 BSC		
L	0.45	0.55	0.65	0.018	0.022	0.026
L1	0		0.15	0		0.006
L2	0.68 REF			0.027 REF		
θ	0°		10°	0°		10°

NOTE

0.50-

6.15

UNIT: mm

0.65

ŧ

4.12

 PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH.
CONTROLLING DIMENSION IS MILLIMETER.

CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.



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